

PMEG4020ER

2 A low V_F MEGA Schottky barrier rectifier Rev. 01 — 22 October 2009

Product data sheet

Product profile

1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a SOD123W small and flat lead Surface-Mounted Device (SMD) plastic package.

1.2 Features

- Average forward current: I_{F(AV)} ≤ 2 A
- Reverse voltage: V_R ≤ 40 V
- Low forward voltage
- High power capability due to clip-bond technology
- AEC-Q101 qualified
- Small and flat lead SMD plastic package

1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch Mode Power Supply (SMPS)
- Reverse polarity protection
- Low power consumption applications

1.4 Quick reference data

Table 1. Quick reference data $T_i = 25 \,^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{F(AV)} avera	average forward current	square wave; $\delta = 0.5$; f = 20 kHz				
		$T_{amb} \le 85 ^{\circ}C$	<u>[1]</u> _	-	2	Α
		T _{sp} ≤ 140 °C	-	-	2	А
V_R	reverse voltage		-	-	40	V
V_{F}	forward voltage	I _F = 2 A	-	430	490	mV
I _R	reverse current	$V_R = 40 V$	-	25	100	μΑ

^[1] Device mounted on a ceramic Printed-Circuit Board (PCB), Al₂O₃, standard footprint.



Pinning information

Table 2. **Pinning**

Pin	Description	Simplified outline	Graphic symbol
1	cathode	[1]	. 64 -
2	anode	1 2	1 - 2
			sym001

^[1] The marking bar indicates the cathode.

Ordering information 3.

Ordering information Table 3.

Type number	Package		
	Name	Description	Version
PMEG4020ER	-	plastic surface-mounted package; 2 leads	SOD123W

Marking

Table 4. **Marking codes**

Type number	Marking code
PMEG4020ER	BE

Limiting values

Table 5. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_R	reverse voltage	$T_j = 25 ^{\circ}C$	-	40	V
I _{F(AV)}	average forward current	square wave; $\delta = 0.5$; f = 20 kHz			
		$T_{amb} \le 85 ^{\circ}C$	<u>[1]</u> _	2	Α
		$T_{sp} \le 140 ^{\circ}C$	-	2	Α
I _{FSM}	non-repetitive peak forward current	square wave; $t_p = 8 \text{ ms}$	[2] -	50	Α
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[3][4]	0.57	W
			[3][5]	0.95	W
			[3][1]	1.8	W

Limiting values ...continued Table 5.

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
T_j	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	+150	°C
T _{stg}	storage temperature		-65	+150	°C

- [1] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.
- [2] $T_i = 25$ °C prior to surge.
- Reflow soldering is the only recommended soldering method.
- [4] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-a)} thermal resistance from junction to ambient		in free air	[1][2]			
		[3] -	-	220	K/W	
			<u>[4]</u> _	-	130	K/W
			[5] _	-	70	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		<u>[6]</u> _	-	18	K/W

- [1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses.
- [2] Reflow soldering is the only recommended soldering method.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [4] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².
- Device mounted on a ceramic PCB, Al₂O₃, standard footprint.
- Soldering point of cathode tab.

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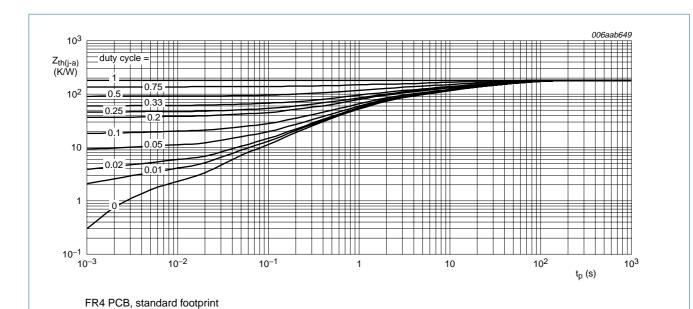


Fig 1. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

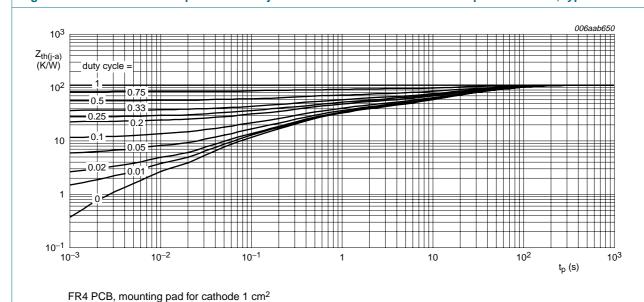
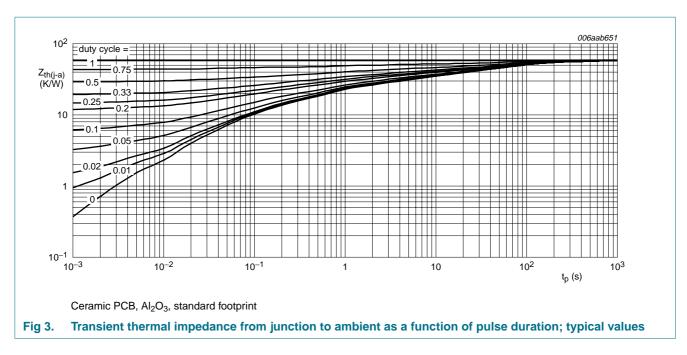


Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

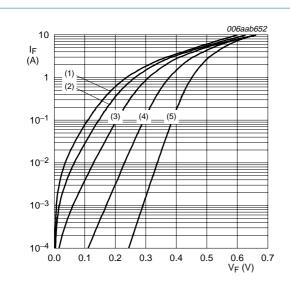


7. Characteristics

Table 7. Characteristics

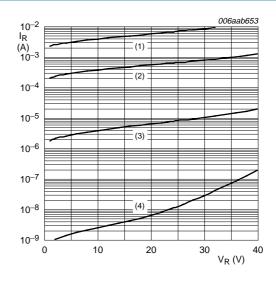
 $T_i = 25 \,^{\circ}C$ unless otherwise specified.

Parameter	Conditions	Min	Тур	Max	Unit
forward voltage	$I_F = 0.1 A$	-	295	330	mV
	I _F = 1 A	-	380	440	mV
	I _F = 2 A	-	430	490	mV
reverse current	$V_R = 10 \text{ V}$	-	5	-	μΑ
	$V_R = 40 V$	-	25	100	μΑ
diode capacitance	f = 1 MHz				
	$V_R = 1 V$	-	250	-	pF
	V _R = 10 V	-	95	-	pF
	forward voltage	$\begin{array}{c} \text{forward voltage} & I_F = 0.1 \text{ A} \\ \hline I_F = 1 \text{ A} \\ \hline I_F = 2 \text{ A} \\ \\ \text{reverse current} & V_R = 10 \text{ V} \\ \hline V_R = 40 \text{ V} \\ \\ \text{diode capacitance} & f = 1 \text{ MHz} \\ \hline V_R = 1 \text{ V} \\ \end{array}$	$ \begin{array}{c} \text{forward voltage} & I_F = 0.1 \text{ A} & - \\ \hline I_F = 1 \text{ A} & - \\ \hline I_F = 2 \text{ A} & - \\ \hline \text{reverse current} & V_R = 10 \text{ V} & - \\ \hline \text{diode capacitance} & f = 1 \text{ MHz} \\ \hline V_R = 1 \text{ V} & - \\ \hline \end{array} $	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$



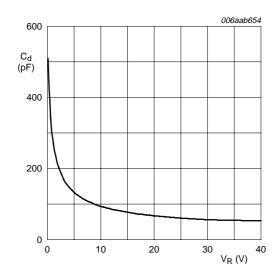
- (1) $T_i = 150 \,^{\circ}\text{C}$
- (2) $T_i = 125 \, ^{\circ}C$
- (3) $T_i = 85 \, ^{\circ}C$
- (4) $T_j = 25 \, ^{\circ}C$
- (5) $T_i = -40 \, ^{\circ}C$





- (1) T_j = 125 °C
- (2) $T_j = 85 \,^{\circ}C$
- (3) $T_j = 25 \,^{\circ}C$
- (4) $T_j = -40 \, ^{\circ}C$

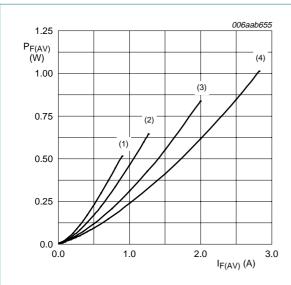
Fig 5. Reverse current as a function of reverse voltage; typical values



f = 1 MHz; T_{amb} = 25 °C

Fig 6. Diode capacitance as a function of reverse voltage; typical values

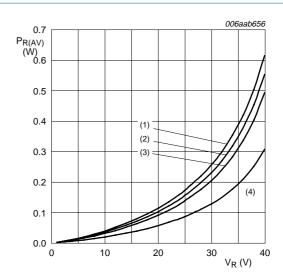
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T_i = 150 °C

- (1) $\delta = 0.1$
- (2) $\delta = 0.2$
- (3) $\delta = 0.5$
- (4) $\delta = 1$

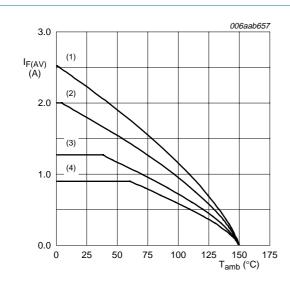
Fig 7. Average forward power dissipation as a function of average forward current; typical values



T_i = 125 °C

- (1) $\delta = 1$
- (2) $\delta = 0.9$
- (3) $\delta = 0.8$
- (4) $\delta = 0.5$

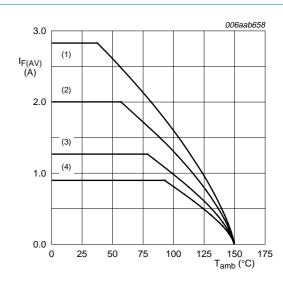
Fig 8. Average reverse power dissipation as a function of reverse voltage; typical values



FR4 PCB, standard footprint

- (1) $\delta = 1$; DC
- (2) $\delta = 0.5$; f = 20 kHz
- (3) $\delta = 0.2$; f = 20 kHz
- (4) $\delta = 0.1$; f = 20 kHz

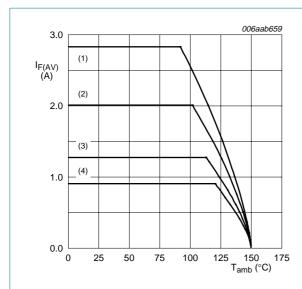
Fig 9. Average forward current as a function of ambient temperature; typical values



FR4 PCB, mounting pad for cathode 1 cm²

- (1) $\delta = 1$; DC
- (2) $\delta = 0.5$; f = 20 kHz
- (3) $\delta = 0.2$; f = 20 kHz
- (4) $\delta = 0.1$; f = 20 kHz

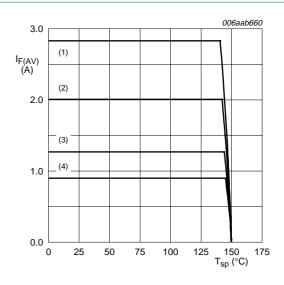
Fig 10. Average forward current as a function of ambient temperature; typical values



Ceramic PCB, Al_2O_3 , standard footprint

- (1) $\delta = 1$; DC
- (2) $\delta = 0.5$; f = 20 kHz
- (3) $\delta = 0.2$; f = 20 kHz
- (4) $\delta = 0.1$; f = 20 kHz

Fig 11. Average forward current as a function of ambient temperature; typical values

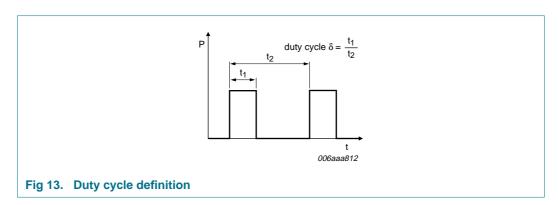


 $T_j = 150 \, ^{\circ}C$

- (1) $\delta = 1$; DC
- (2) $\delta = 0.5$; f = 20 kHz
- (3) $\delta = 0.2$; f = 20 kHz
- (4) $\delta = 0.1$; f = 20 kHz

Fig 12. Average forward current as a function of solder point temperature; typical values

8. Test information



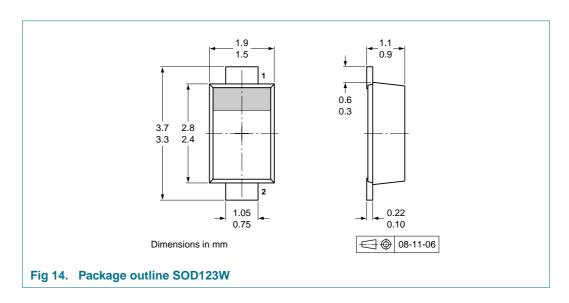
The current ratings for the typical waveforms as shown in Figure 9, 10, 11 and 12 are calculated according to the equations: $I_{F(AV)} = I_M \times \delta$ with I_M defined as peak current,

 $I_{RMS}=I_{F(AV)}$ at DC, and $I_{RMS}=I_{M} imes\sqrt{\delta}$ with I_{RMS} defined as RMS current.

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



10. Packing information

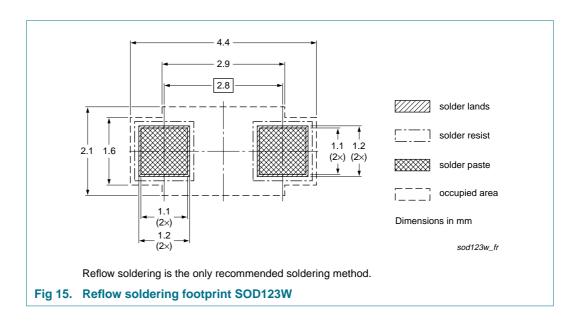
Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity
			3000
PMEG4020ER	SOD123W	4 mm pitch, 8 mm tape and reel	-115

^[1] For further information and the availability of packing methods, see <u>Section 14</u>.

11. Soldering





12. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMEG4020ER_1	20091022	Product data sheet	-	-

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
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14. Contact information

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PMEG4020ER

2 A low V_F MEGA Schottky barrier rectifier

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